PTC/SB/08A(10-01)
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	First Named Inventor	Yin, Zhiping			
	Group Art Unit	Unknown 2891			
	Examiner Name	Unknown WILSON			
Sheet 1 of 1	Attorney Docket No: 3	303.885US1			

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Filing Date	February 27, 2004
First Named Inventor	Yin, Zhiping
Group Art Unit	Unknown 2891
Examiner Name	Unknown WILSON

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	First Named Inventor	Yin, Zhiping			
	Group Art Unit	2891			
	Examiner Name	Wilson, Christian			
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